







TUSB522P

SLLSEV9E - JULY 2016 - REVISED NOVEMBER 2023

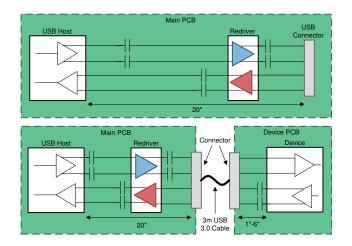
TUSB522P 3.3 V Dual-Channel USB 3.1 GEN 1 Redriver, Equalizer

1 Features

- USB3.1 GEN1 5Gbps, dual-channel re-driver with 3.3-V power supply
- Ultra-low-power architecture:
 - Active: 98 mA
 - U2, U3: 1.2 mA
 - Disconnect 265 µA
 - Shutdown 60 μA
- · Optimal receiver equalization:
 - of 3, 6, 9 dB at 2.5 GHz
- Output driver de-emphasis of 0, 3.5, and 6 dB
- Automatic LFPS de-emphasis control to meet USB 3.1 certification requirements
- No host or device-side requirement
- Hot-plug capable
- Industrial temperature range: -40°C to 85°C TUSB522PI
- Commercial temperature range: 0°C to 70°C TUSB522P

2 Applications

- Cell phones
- **Tablets**
- **Notebooks**
- **Desktops**
- **Docking stations**
- Backplanes and active cables



3 Description

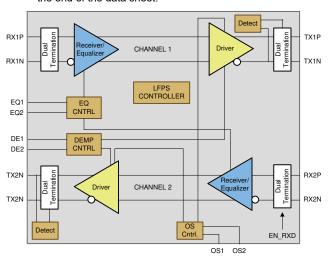
The TUSB522P is a fourth generation, dual-channel, single-lane USB 3.1 GEN1 redriver and signal conditioner supporting 5Gbps. The device offers low power consumption on a 3.3 V supply with its ultralow-power architecture. The redriver also supports the USB 3.1 low power modes, which further reduces idle power consumption.

The dual-channel capability enables the system to maintain signal integrity on both transmit and receive data paths. The receiver equalization has three gain settings to overcome channel degradation from insertion loss and inter-symbol interference. These settings are controlled from the EQ pins. To compensate for transmission line losses, the output driver supports configuration of De-Emphasis with pins DE. Additionally, automatic LFPS De-Emphasis control allows for full USB 3.1 compliance. These settings allow optimal performance, increased signaling distance, and flexibility in placement of the TUSB522P in the USB 3.1 GEN1 path.

Device Information

| PART NUMBER | TEMPERATURE | PACKAGE ⁽¹⁾ |
|-------------|---------------------------------------|------------------------|
| TUSB522P | $T_A = 0$ °C to 70°C | RGE (VQFN, 24) |
| TUSB522PI | $T_A = -40^{\circ}C$ to $85^{\circ}C$ | NGE (VQFN, 24) |

For all available packages, see the orderable addendum at the end of the data sheet.



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Simplified Schematic



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| C | nanges from Revision D (May 2019) to Revision E (November 2023) | Page |
|---|---|----------------|
| • | Updated the numbering format for tables, figures, and cross-references throughout the document | 1 |
| • | Updated the Device Information table to include ambient temperature | 1 |
| • | In the Pin Functions table deleted "Note: When OS = low." for both DE1 and DE2 | |
| • | In Recommended Operation Conditions, changed C _{AC-USB1} max from 200 nF to 265 nF | <mark>5</mark> |
| • | Reformat Table 7-1 for readability | |
| • | Updated Figure 8-1 to include C _{AC-USB1} , C _{AC-USB2} , L _{AB} , L _{CD} , L _{AC-CAP} , L _{ESD} , R _{ESD} , and R _{RX} , | 12 |
| • | Added comment that ac-capacitor should be placed between ESD and USB receptacle when designs short to VBUS protection | |
| • | Updated the <i>Design Parameters</i> table to include pre-channel and post-channel min/max limits | |
| • | Added the ESD Protection section | 14 |
| C | hanges from Revision C (May 2019) to Revision D (May 2019) | Page |
| • | Changed pin 11 From: TX1N To: TX2N and pin 12 From: TX1P To: TX2P in Figure 8-2 | 13 |
| C | hanges from Revision B (November 2017) to Revision C (May 2019) | Page |
| • | Deleted the RGE0024F mechanical pages | 17 |
| C | hanges from Revision A (October 2016) to Revision B (November 2017) | Page |
| • | Changed the values in the FOR OS = HIGH column of Table 7-1 to match FOR OS = LOW column | 11 |
| C | hanges from Revision * (July 2016) to Revision A (October 2016) | Page |
| _ | Changed the device From Preview To: Production | |

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5 Pin Configuration and Functions

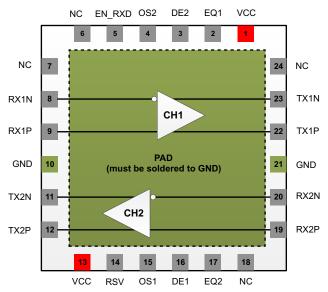


Figure 5-1. RGE Package, 24-Pin (VQFN) (Top View)

Table 5-1. Pin Functions

| | PIN | 1/0 | DESCRIPTION |
|------|-----|----------------|--|
| NAME | NO. | _ | DESCRIPTION |
| RX1N | 8 | Differential I | Differential input for 5Gbps negative signal on Channel 1 |
| RX1P | 9 | Differential I | Differential input for 5Gbps positive signal on Channel 1 |
| TX1N | 23 | Differential O | Differential output for 5Gbps negative signal on Channel 1 |
| TX1P | 22 | Differential O | Differential output for 5Gbps positive signal on Channel 1 |
| RX2N | 20 | Differential I | Differential input for 5Gbps negative signal on Channel 2 |
| RX2P | 19 | Differential I | Differential input for 5Gbps positive signal on Channel 2 |
| TX2N | 11 | Differential O | Differential output for 5Gbps negative signal on Channel 2 |
| TX2P | 12 | Differential O | Differential output for 5Gbps positive signal on Channel 2 |
| EQ1 | 2 | I, CMOS | Sets the receiver equalizer gain for Channel 1. 3-state input with integrated pull-up and pull-down resistors. EQ1 = Low = 3 dB EQ1 = Mid = 6 dB EQ1 = High = 9 dB |
| DE1 | 16 | I, CMOS | Sets the output de-emphasis for Channel 1. 3-state input with integrated pull-up and pull-down resistors. DE1 = Low = 0 dB DE1 = Mid = -3.5 dB DE1 = High = -6.2 dB |
| OS1 | 15 | I, CMOS | Sets the output swing (differential voltage amplitude) for Channel 1. 2-state input with an integrated pull down resistor. OS1 = Low = 0.9 mV OS1 = High = 1.1 mV |
| EQ2 | 17 | I, CMOS | Sets the receiver equalizer gain for Channel 2. 3-state input with integrated pull-up and pull-down resistors. EQ2 = Low = 3 dB EQ2 = Mid = 6 dB EQ2 = High = 9 dB |



Table 5-1. Pin Functions (continued)

| P | riN | | | | |
|--------|--------------|---------|--|--|--|
| NAME | NO. | I/O | DESCRIPTION | | |
| DE2 | 3 | I, CMOS | Sets the output de-emphasis for Channel 2. 3-state input with integrated pull-up and pull-down resistors. DE2 = Low = 0 dB DE2 = Mid = -3.5 dB DE2 = High = -6.2 dB | | |
| OS2 | 4 | I, CMOS | Sets the output swing (differential voltage amplitude) for Channel 2. 2-state input with an integrated pull down resistor. OS2 = Low = 0.9 mV OS2 = High = 1.1 mV | | |
| EN_RXD | 5 | I, CMOS | Enable. The device has a 660-k Ω pulldown resistor. Device is active when EN_RXD = High. Drive actively high or install a pullup resistor (recommend 4.7 K Ω) for normal operation. Does reset state machine. | | |
| RSV | 14 | I, CMOS | Reserved. Can be left as no-connect. | | |
| VCC | 1, 13 | Р | Positive power supply. Power supply is 3.3 V. | | |
| GND | 10, 21, PAD | G | Ground. PAD must be connected to Ground. Pins 10, 21 can be connected to Ground or left unconnected. | | |
| NC | 6, 7, 18, 24 | | No connection. These pins can be tied to any desired voltages including connecting them to GND. | | |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | MIN | MAX | UNIT |
|---|------------------|------|-----|------|
| Supply Voltage Range ⁽²⁾ | V _{CC} | -0.5 | 4 | V |
| Voltage Range at any input or output terminal | Differential I/O | -0.5 | 1.5 | V |
| Voltage Range at any input or output terminal | CMOS Inputs | -0.5 | 4 | V |
| Junction temperature, T _J | | | 105 | °C |
| Storage temperature, T _{stg} | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the GND terminals.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±500 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | NOM | MAX | UNIT |
|----------------------|---|-----------|-----|-----|-----|------|
| V | Main power supply | | 3 | 3.3 | 3.6 | V |
| V _{CC} | Supply Ramp Requirement | | | | 100 | ms |
| V _(PSN) | Supply Noise on V _{CC} Terminals | | | | 100 | mV |
| _ | Operating free air temperature | TUSB522P | 0 | | 70 | °C |
| T _A | Operating free-air temperature | TUSB522PI | -40 | | 85 | °C |
| C _{AC-USB1} | External AC coupling capacitor | | 75 | 100 | 265 | nF |

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

| | | TUSB522P | |
|-----------------------|--|------------|------|
| | THERMAL METRIC(1) | RGE (VQFN) | UNIT |
| | | 24 PINS | |
| R _{0JA} | Junction-to-ambient thermal resistance | 51.2 | °C/W |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 55.9 | °C/W |
| R _{0JB} | Junction-to-board thermal resistance | 28.3 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 2.0 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 28.3 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | 9.7 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics, Power Supply

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|---------------------------------|--|-----|-----|-----|------|
| I _{CC(ACTIVE)} | Average active current | Link in U0 with GEN1 data transmission. RSV, EQ cntrl pins = NC, EN_RXD = V_{CC} , k28.5 pattern at 5Gbps, V_{ID} = 1000 mVpp, OS = 900 mV and DE = 3.5 dB | | 98 | | mA |
| I _{CC(U2U3)} | Average current in U2/U3 | Link in U2 or U3 | | 1.2 | | mA |
| I _{CC(NC)} | Average current disconnect mode | Link in Disconnect mode | | 265 | | μA |
| I _{CC(SHUTDOWN)} | Average shutdown current | EN_RXD = L | | 60 | | μA |

6.6 Electrical Characteristics, DC

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|-------------------------------|--|-----------------------|------------------------|-----------------------|------|
| 3-State (| CMOS Inputs(EQ1/2, DE1/2) | ' | | | | |
| V _{IH} | High-level input voltage | | V _{CC} x 0.8 | | | V |
| V _{IM} | Mid-level input voltage | | | V _{CC} / 2. | | V |
| V _{IL} | Low-level input voltage | | | | V _{CC} x 0.2 | V |
| V _F | Floating voltage | V _{IN} = High impedance | | 0.36 x V _{CC} | | V |
| R _{PU} | Internal pull-up resistance | | | 410 | | kΩ |
| R _{PD} | Internal pull-down resistance | | | 240 | | kΩ |
| I _{IH} | High-level input current | V _{IN} = 3.6 V | | | 26 | μA |
| I _{IL} | Low-level input current | $V_{IN} = GND, V_{CC} = 3.6.V$ | -26 | | | μA |
| 2-State (| CMOS Input (OS1/2, EN_RXD) | | | | | |
| V _{IH} | High-level input voltage | | V _{CC} x 0.7 | | | V |
| V _{IL} | Low-level input voltage | | | | V _{CC} x 0.3 | V |
| R _{PD} | Internal pull-down resistance | | | 660 | | kΩ |
| I _{IH} | Low-level input current | V _{IN} = 3.6 V | | | 25 | μΑ |
| I _{IL} | Low-level input current | V _{IN} = GND, V _{CC} = 3.6.V | -10 | | | μA |



6.7 Electrical Characteristics, AC

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|--|------|------|------|------|
| Differential Receiver (I | RXP, RXN) | | | | | |
| V _(RX-DIFF-PP) | Input differential voltage swing. | AC-coupled differential peak-to-peak signal measured post CTLE through a reference channel | 100 | | 1200 | mVpp |
| V _(RX-DC-CM) | Common-mode voltage bias in the receiver (DC) | | | 0.7 | | V |
| R _(RX-DIFF-DC) | Differential input impedance (DC) | | 72 | | 120 | Ω |
| R _(RX-CM-DC) | Receiver DC Common Mode impedance | Present after a GEN1 device is detected on TXP/TXN | 18 | | 30 | Ω |
| Z _(RX-HIGH-IMP-DC-POS) | Common-mode input impedance with termination disabled (DC) | Present when no GEN1 device is detected on TXP/TXN. Measured over the range of 0-500 mV with respect to GND. | 25 | | | kΩ |
| V _(RX-SIGNAL-DET-DIFF-PP) | Input Differential peak-to-peak Signal Detect Assert Level | At 5Gbps, no input channel loss clock | | 85 | | mV |
| V _(RX-IDLE-DET-DIFF-PP) | Input Differential peak-to-peak Signal Detect De-assert Level | pattern | | 85 | | mV |
| V _(RX-LFPS-DET-DIFF-PP) | Low Frequency Periodic Signaling (LFPS) Detect Threshold | Below the minimum is squelched. | 100 | | 300 | mV |
| V _(RX-CM-AC-P) | Peak RX AC common mode voltage | Measured at package pin | | | 150 | mV |
| V _(detect) | Voltage change to allow receiver detect | Positive voltage to sense receiver termination | | | 600 | mV |
| C _(RX-PARASITIC) | Voltage change to allow receiver detect | At 2.5 GHz | 0.17 | 0.63 | 0.99 | pF |
| P | Differential Return Loss | 50 MHz – 1.25 GHz at 90 Ω | | -19 | | dB |
| $R_{L(RX-DIFF)}$ | Differential Neturn Loss | 2.5 GHz at 90 Ω | | -14 | | dB |
| R _{L(RX-CM)} | Common Mode Return Loss | 50 MHz – 1.25 GHz at 90 Ω | | -13 | | dB |
| Differential Transmitte | r (TXP, TXN) | | | | | |
| | Transmitter differential voltage swing | OS Low, 0dB DE | 0.8 | 0.9 | | Vpp |
| *(TX-DIFF-PP) | (transition-bit) | OS High, 0dB DE | | 1.1 | 1.2 | Vpp |
| $V_{(TX-DIFF-PP-LFPS)}$ | LFPS differential voltage swing | OS Low, High | 0.8 | | 1.2 | Vpp |
| | | DE = Low | | 0 | | dB |
| V _(TX-DE-RATIO) | Transmitter differential voltage De- Emphasis ratio | DE = Floating | | -3.5 | | dB |
| | | DE = High | | -6.2 | | dB |
| V _(TX-RCV-DETECT) | Amount of voltage change allowed during Receiver Detection | | | | 600 | mV |
| V _(TX-CM-IDLE-DELTA) | Transmitter idle common-mode voltage change while in U2/U3 and not actively transmitting LFPS | | -600 | | 600 | mV |
| V _(TX-DC-CM) | Common-mode voltage bias in the transmitter (DC) | | | 0.7 | | V |
| V _(TX-CM-AC-PP-ACTIVE) | Tx AC Common-mode voltage active | Max mismatch from Txp + Txn for both time and amplitude | | | 100 | mVpp |
| V _(TX-IDLE-DIFF-AC-PP) | AC Electrical idle differential peak-to- peak output voltage | At package pins | 0 | | 10 | mV |
| V _(TX-IDLE-DIFF-DC) | DC Electrical idle differential output voltage | At package pins after low pass filter to remove AC component | 0 | | 10 | mV |
| V _(TX-CM-DC-ACTIVE-IDLE-DELTA) | Absolute DC common mode voltage between U1 and U0 | At package pin | | | 200 | mV |
| C _(TX) | TX input capacitance to GND | At 2.5 GHz | | | 1.25 | pF |
| R _(TX-DIFF) | Differential impedance of the driver | | 72 | | 120 | Ω |
| R _(TX-CM) | Common-mode impedance of the driver | Measured with respect to AC ground over 0-500 mV | 18 | | 30 | Ω |
| I _(TX-SHORT) | TX short circuit current | TX± shorted to GND | | | 60 | mA |
| C _(TX-PARASITIC) | TX input capacitance for return loss | Package Pins | | 0.63 | 1.02 | F |



6.7 Electrical Characteristics, AC (continued)

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------------------|---|--|-----|-----|-----|------|
| D | Differential Determine | 50 MHz – 1.25 GHz at 90 Ω | | 12 | | dB |
| $R_{L(RX-DIFF)}$ | Differential Return Loss | 1.25 – 2.5 GHz at 90 Ω | | 8 | | dB |
| D | Common Mode Return Loss | 50 MHz – 1.25 GHz at 90 Ω | | 13 | | dB |
| R _{L(RX-CM)} | Common Mode Return Loss | 1.25 –2.5 GHz | | 11 | | dB |
| AC Characteristic | | | | | | |
| Xtalk | Differential Cross Talk between TX and RX signal Pairs | At 2.5 GHz | | -40 | | dB |
| V _(CM-TX-AC) | AC Common-mode voltage swing in active mode | Within U0 and within LFPS | | | 100 | mVpp |
| V _{(TX-IDLE-DIFF} -AC-PP) | Differential voltage swing during electrical idle | Tested with a high-pass filter | 0 | | 10 | V |
| D | Differential Return Loss | f = 50 MHz - 1.25 GHz | | 12 | | dB |
| $R_{L(TX-DIFF)}$ | Differential Return Loss | 1.25 –2.5 GHz | | 8 | | dB |
| D | Common Mode Return Loss | f = 50 MHz - 1.25 GHz | | 16 | | dB |
| $R_{L(TX-CM)}$ | Common wode Return Loss | 1.25 –2.5 GHz | | 13 | | dB |
| t _J | Total Jitter | Minimum input and output trace at 2.5 GHz, V _{CC} = 3.3 V | | 15 | | ps |
| V _(TX-CM-ΔU1-U0) | Absolute delta of DC CM voltage during active and idle states | | | | 100 | mV |
| V _(TX-IDLE-DIFF-DC) | DC Electrical idle differential output voltage | Voltage must be low pass filtered to remove any AC component | 0 | | 12 | mV |

Product Folder Links: TUSB522P

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7 Detailed Description

7.1 Overview

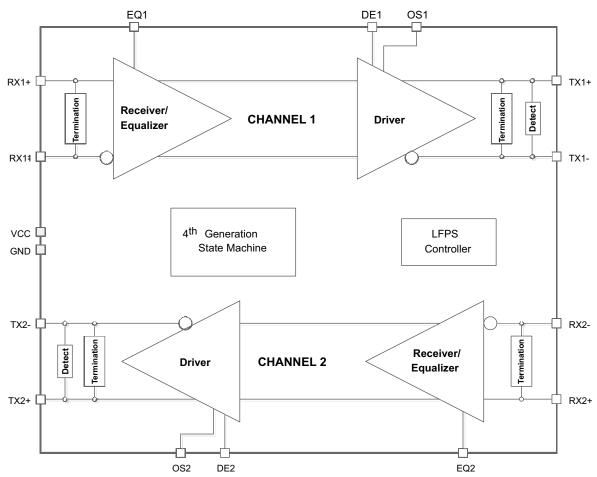
The TUSB522P is designed to overcome channel loss due to inter-symbol interference and crosstalk when 5Gbps USB3.1 GEN1 signals travel across a PCB or cable. The dual channel architecture is a one-chip, low-power solution, extending the possible channel length for transmit and receive data paths in an application. For a Host application, this enables the system to pass both transmitter compliance and receiver jitter tolerance tests.

The re-driver recovers incoming data by applying equalization that compensates for channel loss, and drives out signals with a high differential voltage. Each channel has a receiver equalizer with selectable gain settings. The equalization should be set based on the amount of insertion loss in channel 1 or 2 before the TUSB522P receivers. Likewise, the output drivers support configuration of De-Emphasis. Independent equalization and de-emphasis control for each channel can be set using EQ1/2 and DE1/2 pins.

The TUSB522P advanced state machine makes it transparent to hosts and devices. After power up, the TUSB522P periodically performs receiver detection on the TX pairs. If it detects a USB3.1 GEN1 receiver, the RX termination is enabled, and the TUSB522P is ready to re-drive.

The device ultra-low-power architecture operates at a 3.3-V power supply and achieves Enhanced performance. The automatic LFPS De-Emphasis control further enables the system to be USB3.1 compliant.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Receiver Equalization

The purpose of receiver equalization is to compensate for channel insertion loss and inter-symbol interference in the system before the input of the TUSB522P. The receiver overcomes these losses by attenuating the low frequency components of the signals with respect to the high frequency components. The proper gain setting should be selected to match the channel insertion loss before the input of the TUSB522P receivers. The gain setting may differ for channel 1 and channel 2.

7.3.2 De-Emphasis Control and Output Swing

The differential driver output provides selectable de-emphasis and output swing control in order to achieve USB3.1 compliance. The TUSB522P offers a unique way to adjust output de-emphasis and transmitter swing based on the OS1/2 and DE1/2 pins. The level of de-emphasis required in the system depends on the channel length after the output of the re-driver. The output swing and de-emphasis levels may differ for channel 1 and channel 2.

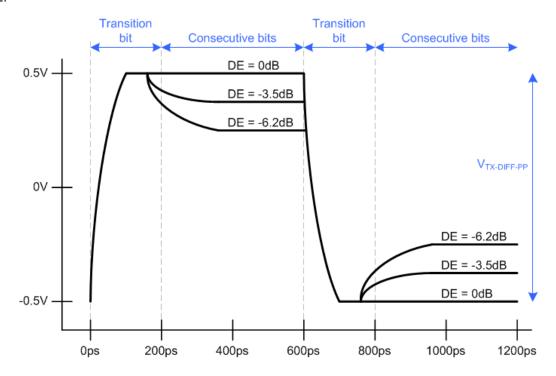


Figure 7-1. Transmitter Differential Voltage, OS = Floating

7.3.3 Automatic LFPS Detection

The TUSB522P features an intelligent low frequency periodic signaling (LFPS) controller. The controller senses the low frequency signals and automatically disables the driver de-emphasis, for full USB3.1 compliance.

7.4 Device Functional Modes

7.4.1 Device Configuration

Table 7-1. Control Pin Settings (Typical Values)

| PIN | PIN DESCRIPTION | | TYP | UNITS |
|---------|---|----------|------|-------|
| | | Low | 3 | dB |
| EQ1/EQ2 | Receiver equalization amount | Floating | 6 | dB |
| | | High | 9 | dB |
| OS1/OS2 | Transmit output swing amplitude for the | Low | 0.9 | Vpp |
| 031/032 | transition bit | High | 1.1 | Vpp |
| | | Low | 0 | dB |
| DE1/DE2 | Transmit de-emphasis amount | Floating | -3.5 | dB |
| | | High | -6.2 | dB |

7.4.2 Power Modes

The TUSB522P has 3 primary power modes:

7.4.2.1 U0 Mode (Active Power Mode)

During active power mode, U0, the device is transmitting USB SS data or USB LFPS signaling. The U0 mode is the highest power state of the TUSB522P. Anytime super-speed traffic is being received, the TUSB522P remains in this mode.

7.4.2.2 U2/U3 (Low Power Mode)

While in this mode, the TUSB522P periodically performs far-end receiver detection.

7.4.2.3 Disconnect Mode - RX Detect

In this state, the TUSB522P periodically checks for far-end receiver termination on both TX. Upon detection of the far-end receiver's termination on both ports, the TUSB522P will transition to U0 mode.

Product Folder Links: TUSB522P

7.4.2.4 Shutdown Mode

Shutdown mode is entered when the EN_RXD pin is driven low. This is lowest power setting for the device.

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TUSB522P is a dual-channel single-lane re-driver and signal conditioner designed to compensate for ISI jitter caused by attenuation through passive mediums such as traces or cables. The TUSB522P has two independent channels to allow optimization in both upstream and downstream directions through three EQ and six De-Emphasis settings.

8.2 Typical Application

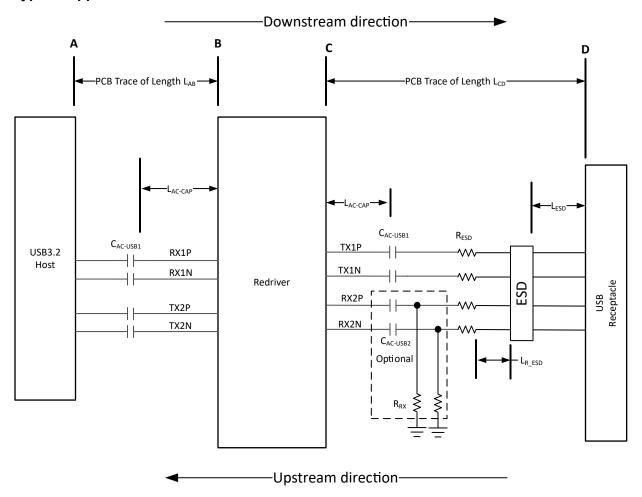


Figure 8-1. Embedded Host Application

The $C_{AC\text{-}USB1}$ and $C_{AC\text{-}USB2}$ should be placed between ESD and USB receptacle for systems designing for short to VBUS protection.

8.2.1 Design Requirements

For this design example, use the parameters provided in Table 8-1.

Table 8-1. Design Parameters

| PARAMETER | VALUE |
|--|--|
| Pre-channel A to B PCB trace length ⁽¹⁾ , L _{AB} . | 1 inches ≤ L _{AB} ≤ 20 inches |
| Post-channel C to D PCB trace length ⁽¹⁾ , L _{CD} . | ≤ 6 inches |
| Minimum distance of the AC capacitors from TUSB522P, L _{AC-CAP} | 0.25 inches |
| Maximum distance of ESD component from the USB receptacle, L _{ESD} | 0.6 inches |
| Maximum distance of series resistor (R_{ESD}) from ESD component, $L_{R_{ESD}}$. | 0.25 inches |
| C _{AC-USB1} AC-coupling capacitor (75 nF to 265 nF) | 100 nF |
| C _{AC-USB2} AC-coupling capacitor (297 nF to 363 nF) | Options: |
| | RX1 or RX2 are DC-coupled to USB receptacle |
| | 330 nF AC-couple with R _{RX} resistor |
| Optional R _{RX} resistor (220-kΩ ± 5%) | Not used |
| Optional R _{ESD} $(0-\Omega \text{ to } 2.2-\Omega)$ | Not used |
| V _{CC} supply (3-V to 3.6-V) | 3.3-V |
| EQ1 for RX1P/N (3, 6, or 9dB) | 9 dB (EQ1 = High) |
| De-Emphasis 2 for TX2P/N (0, -3.5, and - 6.2 dB) | -6.2 dB (OS2 = Low, DE2 = High) |
| EQ2 for RX2P/N (3, 6, or 9 dB) | 6 dB (EQ2 = Floating) |
| De-Emphasis 1 for TX1P/N (0, -3.5, and -6.2 dB) | -3.5 dB (OS1 = Low, DE1 = Floating) |
| Output Swing 1 (0.9 or 1.1 Vppd) | 900 mV (OS1 = Low) |
| Output Swing 2 (0.9 or 1.1 Vppd) | 900 mV (OS2 = Low) |

⁽¹⁾ Maximum trace length assumes an insertion loss of 0.2 dB/inch/GHz. If insertion loss is more than 0.2 dB/inch/GHz, then maximum trace length must be reduced accordingly.

8.2.2 Detailed Design Procedure

The TUSB522P differential receivers and transmitters have internal BIAS and termination. Due to this, the TUSB522P must be connected to the USB Host and receptacle through ac-coupling capacitors. In this example, as depicted in Figure 8-2, 100 nF capacitors are placed on TX2P, TX2N, RX1P, RX1N, TX1P and TX1N. No ac-coupling capacitors are placed on the RX2P and RX2N pins because it is assumed the device downstream of the TUSB522P will have ac-coupling capacitors on its transmitter as defined by the USB 3.1 specification. The system designer may desire to support short to VBUS protection. If this is the case, then a 330 nF ac-coupling capacitor should be placed on RX2P/N pins.



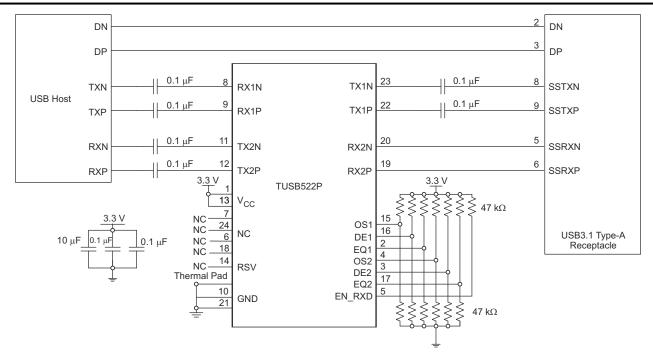


Figure 8-2. Embedded Host Application Schematic

8.2.2.1 ESD Protection

It may be necessary to incorporate an ESD component to protect the TUSB522P from electrostatic discharge (ESD). It is recommended that the ESD protection component has working peak voltage of \geq 1.3 V, a breakdown voltage of \geq 2.3 V, and a clamp voltage of \leq 4.0 V. A clamp voltage greater than 4.0 V may require a R_{ESD} on each differential pin. The ESD component should be placed near the USB connector.

Table 8-2. Recommended ESD Protection Component

| Manufacturer | Part Number | Required R _{ESD} to pass IEC 61000-4-2 Contact ±8-kV | | |
|--------------|--------------|---|--|--|
| Nexperia | PUSB3FR4 | 2.2-Ω | | |
| Nexperia | PESD2V8Y1BSF | 2.2-Ω | | |

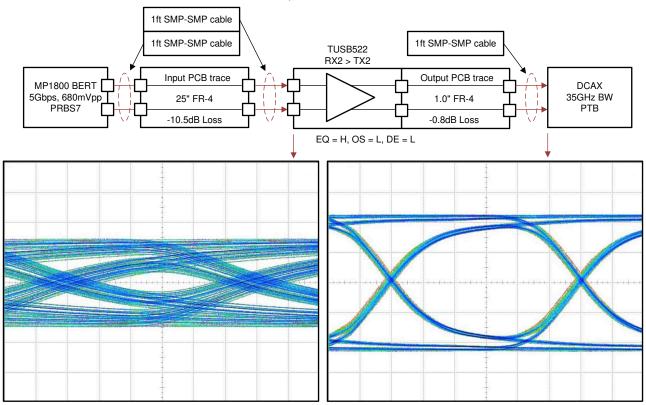
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8.2.3 Application Curves

BERT > 24"6mil > char-board > RX2-to-TX2 > char-board > Scope



8.3 Power Supply Recommendations

The TUSB522P is designed to operate with a 3.3-V power supply. Levels above those listed in the *Absolute Ratings* table should not be used. If using a higher voltage system power supply, a voltage regulator can be used to step down to 3.3 V. Decoupling capacitors should be used to reduce noise and improve power supply integrity. A 0.1-µF capacitor should be used on each power pin.

8.4 Layout

8.4.1 Layout Guidelines

- RXP/N and TXP/N pairs should be routed with controlled 90-Ω differential impedance (±15%).
- Keep away from other high speed signals.
- Intra-pair routing should be kept to within 2mils.
- Length matching should be near the location of mismatch.
- Each pair should be separated at least by 3 times the signal trace width.
- The use of bends in differential traces should be kept to a minimum. When bends are used, the number of left and right bends should be as equal as possible and the angle of the bend should be ≥ 135 degrees. This will minimize any length mismatch causes by the bends and therefore minimize the impact bends have on EMI.
- Route all differential pairs on the same of layer.
- The number of VIAS should be kept to a minimum. It is recommended to keep the VIAS count to 2 or less.
- Keep traces on layers adjacent to ground plane.
- Do not route differential pairs over any plane split.
- Adding test points will cause impedance discontinuity; and will therefore, negatively impact signal
 performance. If test points are used, they should be placed in series and symmetrically. They must not
 be placed in a manner that causes a stub on the differential pair.
- The 100-nF capacitors on the TXP and SSTXN nets must be placed close to the USB connector (Type A, Type B, and so forth).

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- The ESD and EMI protection devices (if used) must also be placed as close as possible to the USB connector.
- · Place voltage regulators as far away as possible from the differential pairs.
- To minimize crosstalk, TI recommends keeping high-speed signals away from each other. Each pair must be separated by at least 5 times the signal trace width. Separating with ground also helps minimize crosstalk.

8.4.2 Layout Example

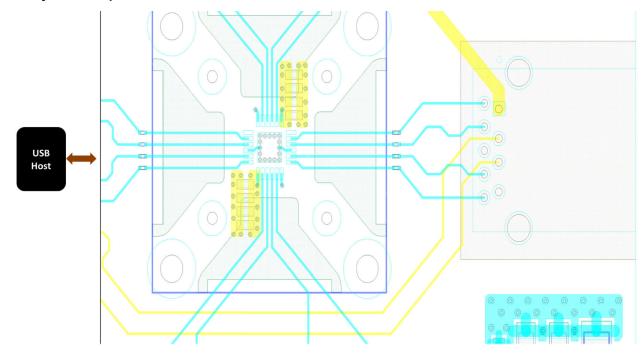


Figure 8-3. Example Layout

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9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: TUSB522P

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PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| TUSB522PIRGER | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PIRGER.A | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PIRGERG4.A | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PIRGET | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PIRGET.A | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PRGER | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TUSB 522P |
| TUSB522PRGER.A | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PRGET | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TUSB 522P |
| TUSB522PRGET.A | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |
| TUSB522PRGETG4.A | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TUSB 522P |

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS Reel Diameter Reel Width (W1)



| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TUSB522PIRGER | VQFN | RGE | 24 | 3000 | 330.0 | 12.4 | 4.25 | 4.25 | 1.15 | 8.0 | 12.0 | Q2 |
| TUSB522PIRGET | VQFN | RGE | 24 | 250 | 180.0 | 12.4 | 4.25 | 4.25 | 1.15 | 8.0 | 12.0 | Q2 |
| TUSB522PRGER | VQFN | RGE | 24 | 3000 | 330.0 | 12.4 | 4.25 | 4.25 | 1.15 | 8.0 | 12.0 | Q2 |
| TUSB522PRGET | VQFN | RGE | 24 | 250 | 180.0 | 12.4 | 4.25 | 4.25 | 1.15 | 8.0 | 12.0 | Q2 |



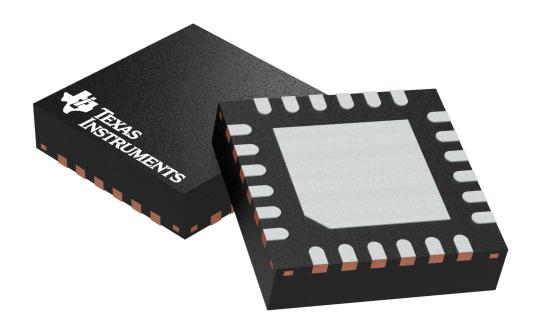
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*All dimensions are nominal

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|--------------------------------------|---------------------------|-----|------|------|-------------|------------|-------------|
| Device | Package Type Package Draw | | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| TUSB522PIRGER | VQFN | RGE | 24 | 3000 | 356.0 | 356.0 | 35.0 |
| TUSB522PIRGET | VQFN | RGE | 24 | 250 | 210.0 | 185.0 | 35.0 |
| TUSB522PRGER | VQFN | RGE | 24 | 3000 | 356.0 | 356.0 | 35.0 |
| TUSB522PRGET | VQFN | RGE | 24 | 250 | 210.0 | 185.0 | 35.0 |

PLASTIC QUAD FLATPACK - NO LEAD

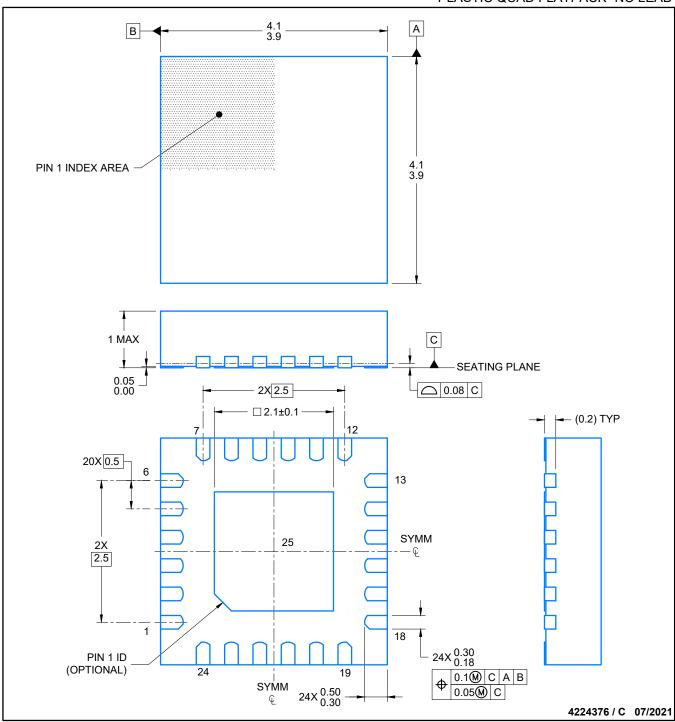


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

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PLASTIC QUAD FLATPACK- NO LEAD

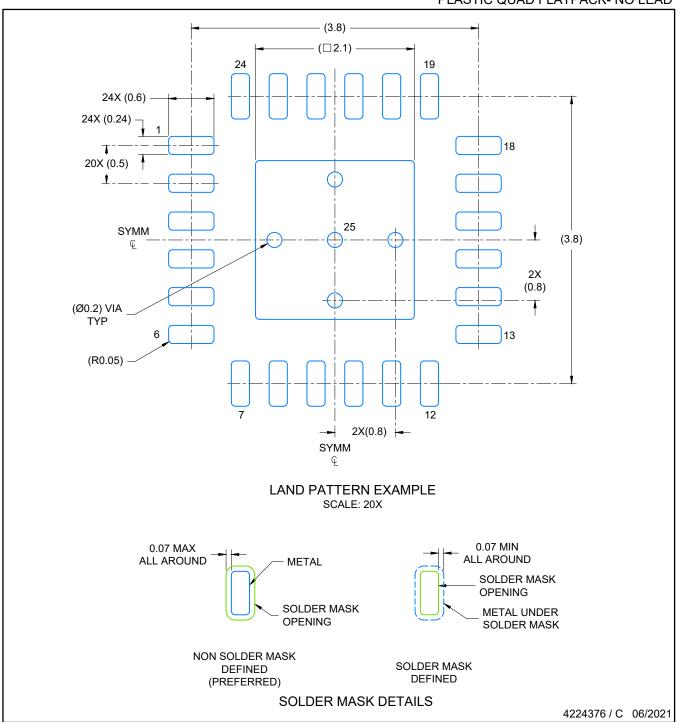


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK- NO LEAD

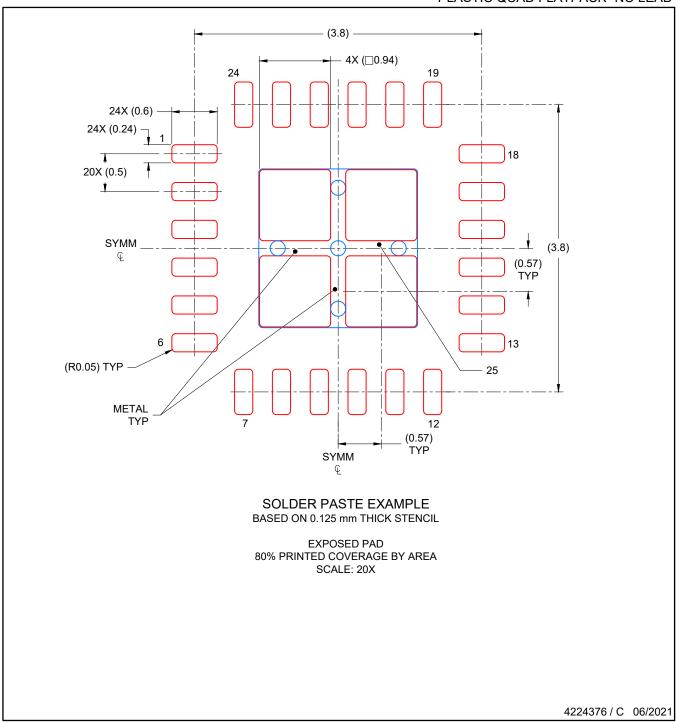


NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments
 literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..

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